

# FDD1600N10ALZ

## N-Channel PowerTrench® MOSFET

100V, 6.8A, 160mΩ

### Features

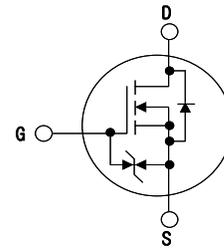
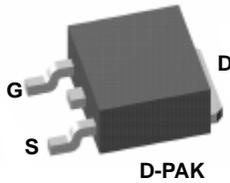
- $R_{DS(on)} = 124m\Omega$  (Typ.) @  $V_{GS} = 10V, I_D = 3.5A$
- $R_{DS(on)} = 175m\Omega$  (Typ.) @  $V_{GS} = 5.0V, I_D = 2.1A$
- Low Gate Charge (Typ. 2.78nC)
- Low  $C_{rss}$  (Typ. 2.04pF)
- Fast Switching
- 100% Avalanche Tested
- Improved dv/dt Capability
- RoHS Compliant

### Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advance PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

### Application

- DC to DC Converters
- Synchronous Rectification for Telecommunication PSU
- Battery Charger
- AC motor drives and Uninterruptible Power Supplies



### MOSFET Maximum Ratings $T_C = 25^\circ C$ unless otherwise noted

Symbol	Parameter	FDD1600N10ALZ	Units
$V_{DSS}$	Drain to Source Voltage	100	V
$V_{GSS}$	Gate to Source Voltage	$\pm 20$	V
$I_D$	Drain Current	- Continuous ( $T_C = 25^\circ C$ )	6.8
		- Continuous ( $T_C = 100^\circ C$ )	4.3
$I_{DM}$	Drain Current	- Pulsed (Note 1)	27.2
$E_{AS}$	Single Pulsed Avalanche Energy	(Note 2)	5.08
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	6.0
$P_D$	Power Dissipation	( $T_C = 25^\circ C$ )	14.9
		- Derate above $25^\circ C$	0.12
$T_J, T_{STG}$	Operating and Storage Temperature Range	-55 to +150	$^\circ C$
$T_L$	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds	300	$^\circ C$

### Thermal Characteristics

Symbol	Parameter	FDD1600N10ALZ	Units
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max	8.4	$^\circ C/W$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max	87	

## Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
1600N10ALZ	FDD1600N10ALZ	D-PAK	380mm	16mm	2500

## Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
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### Off Characteristics

$BV_{DSS}$	Drain to Source Breakdown Voltage	$I_D = 250\mu\text{A}$ , $V_{GS} = 0\text{V}$ , $T_C = 25^\circ\text{C}$	100	-	-	V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250\mu\text{A}$ , Referenced to $25^\circ\text{C}$	-	0.1	-	$\text{V}/^\circ\text{C}$
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 80\text{V}$ , $V_{GS} = 0\text{V}$ $V_{DS} = 80\text{V}$ , $T_C = 125^\circ\text{C}$	-	-	1 500	$\mu\text{A}$
$I_{GSS}$	Gate to Body Leakage Current	$V_{GS} = \pm 20\text{V}$ , $V_{DS} = 0\text{V}$	-	-	$\pm 10$	$\mu\text{A}$

### On Characteristics

$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 250\mu\text{A}$	1.4	2.1	2.8	V
$R_{DS(on)}$	Static Drain to Source On Resistance	$V_{GS} = 10\text{V}$ , $I_D = 3.5\text{A}$ $V_{GS} = 5\text{V}$ , $I_D = 2.1\text{A}$	-	124	160	$\text{m}\Omega$
$g_{FS}$	Forward Transconductance	$V_{DS} = 10\text{V}$ , $I_D = 6.8\text{A}$	-	34	-	S

### Dynamic Characteristics

$C_{iss}$	Input Capacitance	$V_{DS} = 50\text{V}$ , $V_{GS} = 0\text{V}$ $f = 1\text{MHz}$	-	169	225	pF
$C_{oss}$	Output Capacitance		-	43	55	pF
$C_{riss}$	Reverse Transfer Capacitance		-	2.04	-	pF
$C_{oss(er)}$	Energy Related Output Capacitance	$V_{DS} = 50\text{V}$ , $I_D = 6.8\text{A}$	-	85	-	pF
$Q_{g(tot)}$	Total Gate Charge at 10V	$V_{DS} = 50\text{V}$ , $I_D = 6.8\text{A}$ $V_{GS} = 10\text{V}$	-	2.78	3.61	nC
$Q_{g(tot)}$	Total Gate Charge at 5V		-	1.5	1.95	nC
$Q_{gs}$	Gate to Source Gate Charge		-	0.72	-	nC
$Q_{gd}$	Gate to Drain "Miller" Charge		(Note 4)	-	0.56	-
ESR	Equivalent Series Resistance (G-S)	$f = 1\text{MHz}$	-	2.1	-	$\Omega$

### Switching Characteristics

$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 50\text{V}$ , $I_D = 6.8\text{A}$ $V_{GS} = 10\text{V}$ , $R_{GEN} = 4.7\Omega$	-	7	24	ns
$t_r$	Turn-On Rise Time		-	2	14	ns
$t_{d(off)}$	Turn-Off Delay Time		-	13	36	ns
$t_f$	Turn-Off Fall Time		(Note 4)	-	2	14

### Drain-Source Diode Characteristics

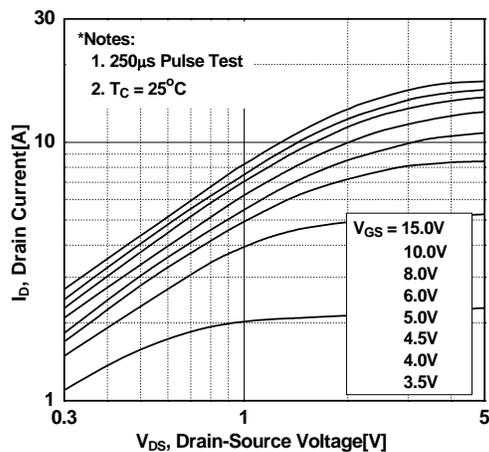
$I_S$	Maximum Continuous Drain to Source Diode Forward Current	-	-	6.8	A	
$I_{SM}$	Maximum Pulsed Drain to Source Diode Forward Current	-	-	27.2	A	
$V_{SD}$	Drain to Source Diode Forward Voltage	$V_{GS} = 0\text{V}$ , $I_{SD} = 6.8\text{A}$	-	-	1.3	V
$t_{rr}$	Reverse Recovery Time	$V_{GS} = 0\text{V}$ , $I_{SD} = 6.8\text{A}$ , $V_{DS} = 50\text{V}$	-	37	-	ns
$Q_{rr}$	Reverse Recovery Charge	$di_F/dt = 100\text{A}/\mu\text{s}$	-	42	-	nC

#### Notes:

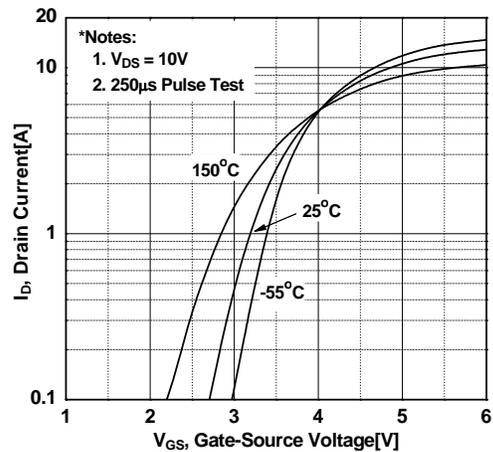
1. Repetitive Rating: Pulse width limited by maximum junction temperature
2.  $L = 1\text{mH}$ ,  $I_{AS} = 3.18\text{A}$ ,  $R_G = 25\Omega$ , Starting  $T_J = 25^\circ\text{C}$
3.  $I_{SD} \leq 6.8\text{A}$ ,  $di/dt \leq 200\text{A}/\mu\text{s}$ ,  $V_{DD} \leq BV_{DSS}$ , Starting  $T_J = 25^\circ\text{C}$
4. Essentially Independent of Operating Temperature Typical Characteristics

## Typical Performance Characteristics

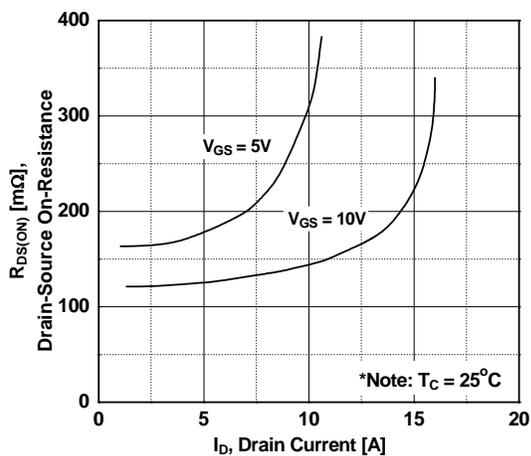
**Figure 1. On-Region Characteristics**



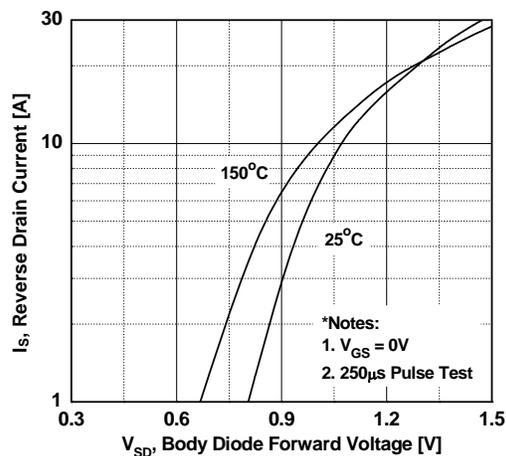
**Figure 2. Transfer Characteristics**



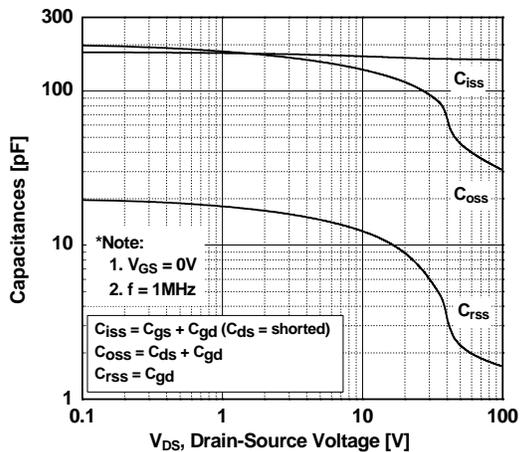
**Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage**



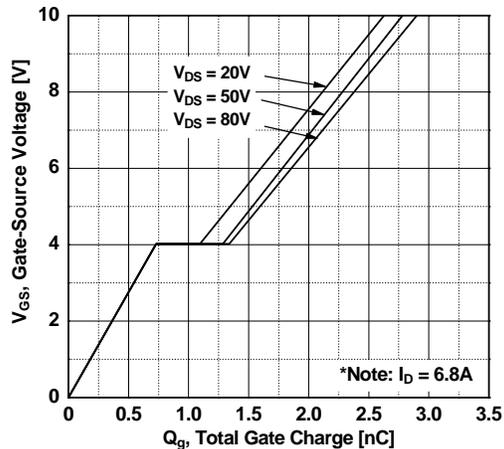
**Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature**



**Figure 5. Capacitance Characteristics**



**Figure 6. Gate Charge Characteristics**



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

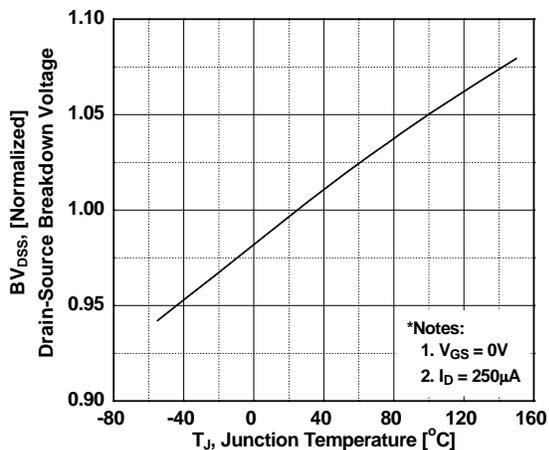


Figure 8. On-Resistance Variation vs. Temperature

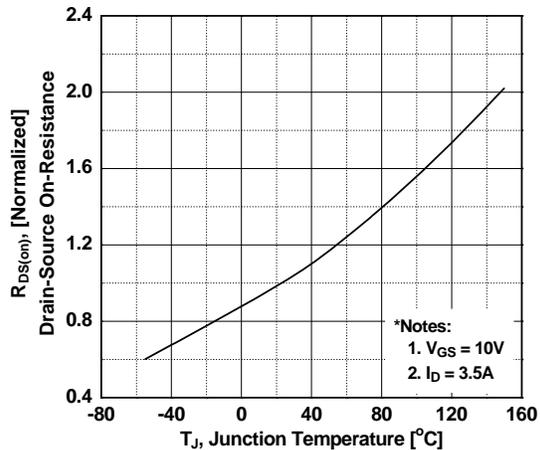


Figure 9. Maximum Safe Operating Area vs. Case Temperature

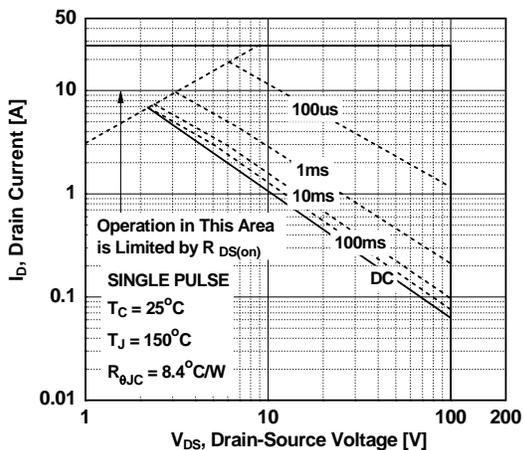


Figure 10. Maximum Drain Current

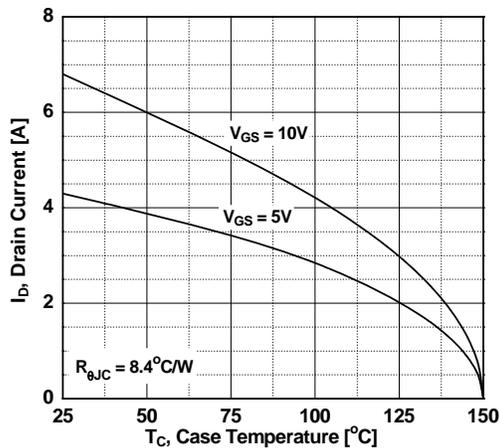


Figure 11. E\_oss vs. Drain to Source Voltage

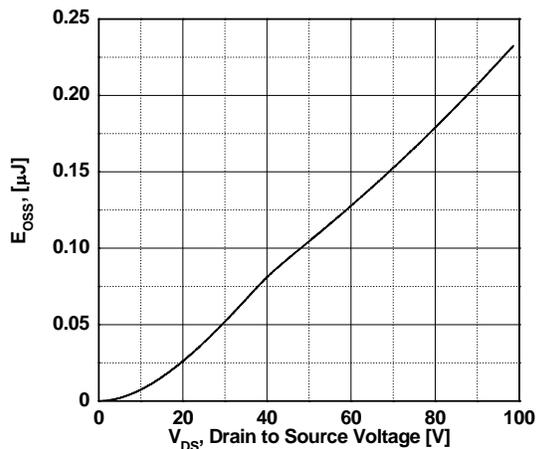
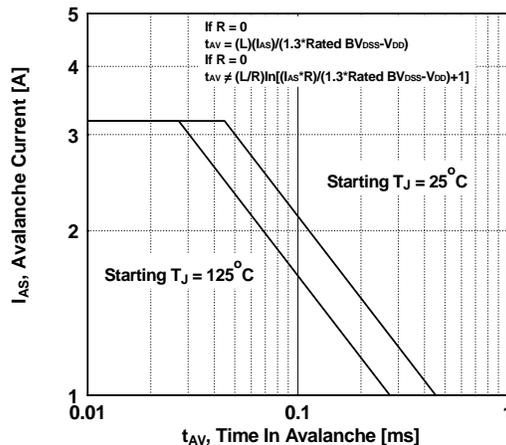
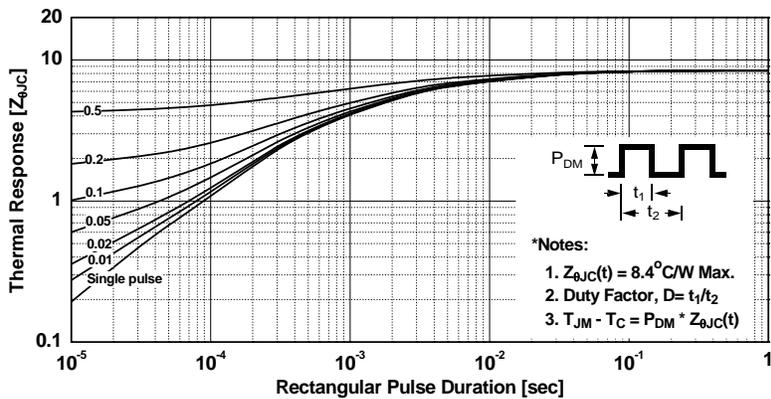


Figure 12. Unclamped Inductive Switching Capability

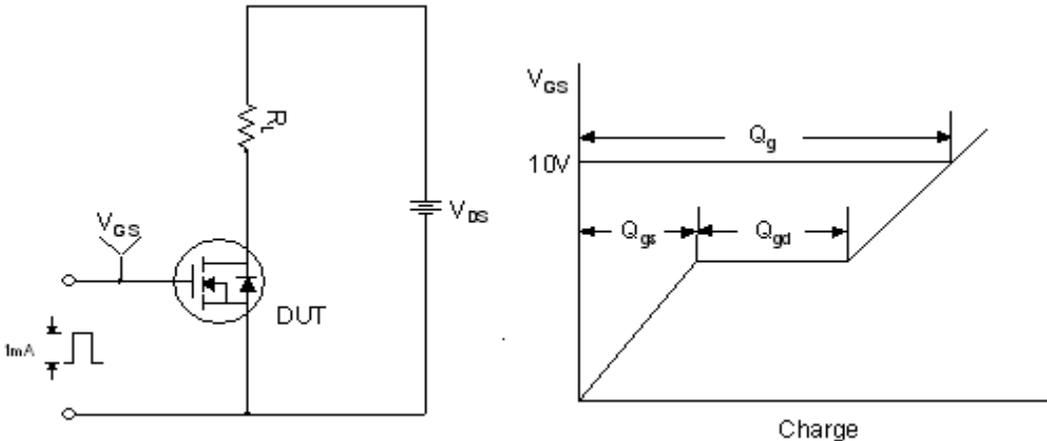


Typical Performance Characteristics (Continued)

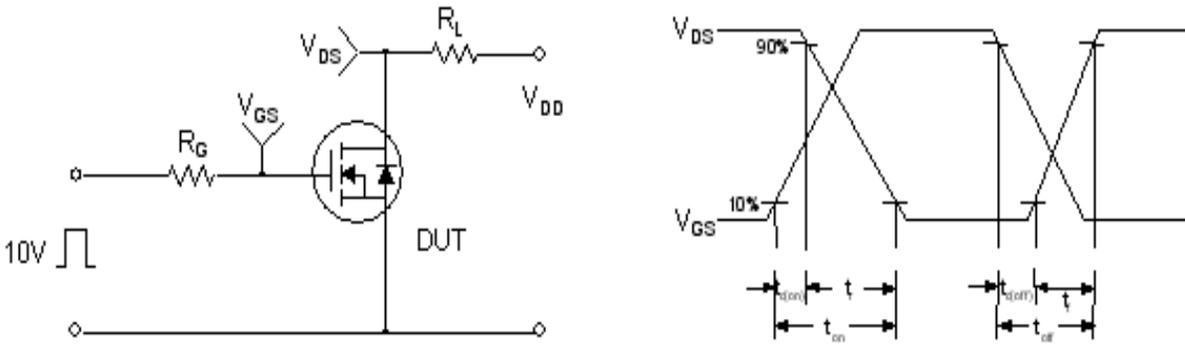
Figure 13. Transient Thermal Response Curve



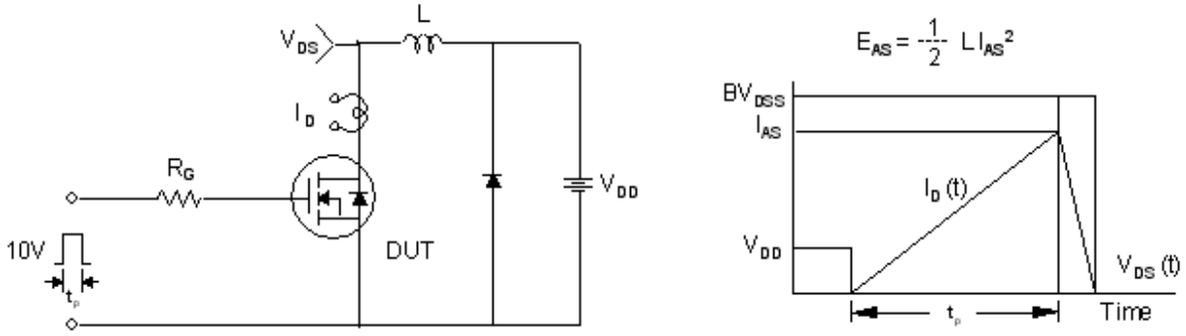
**Gate Charge Test Circuit & Waveform**



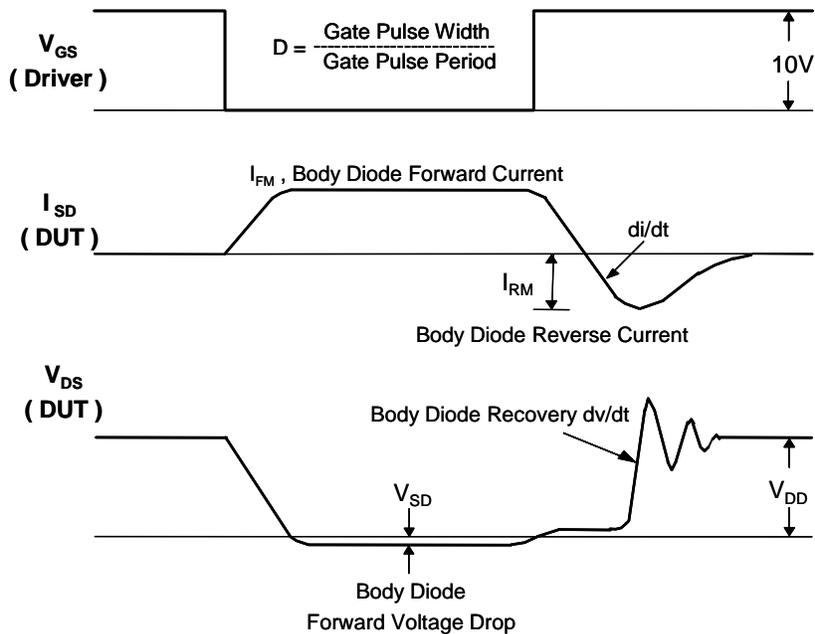
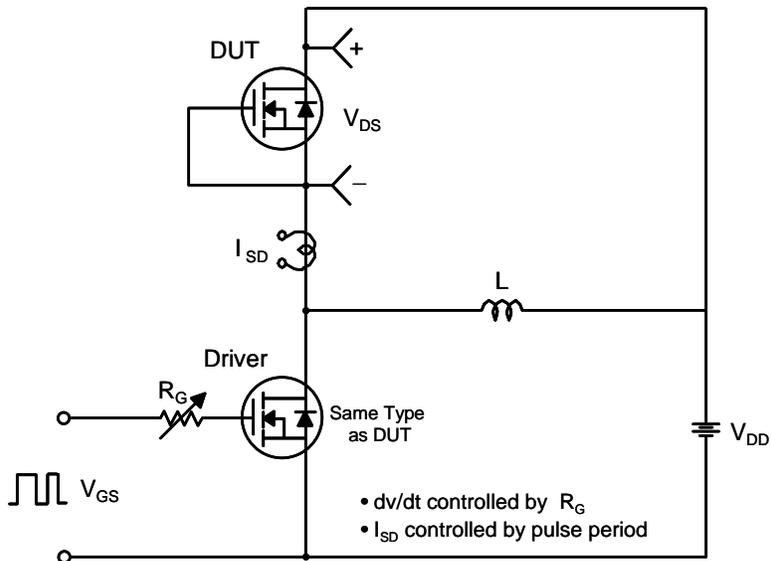
**Resistive Switching Test Circuit & Waveforms**



**Unclamped Inductive Switching Test Circuit & Waveforms**

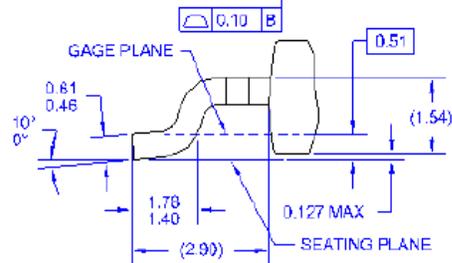
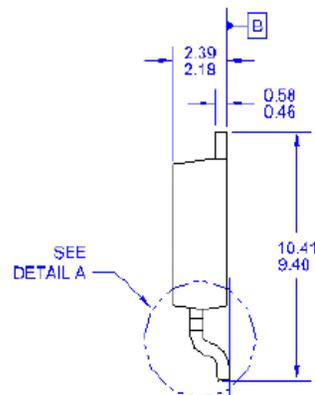
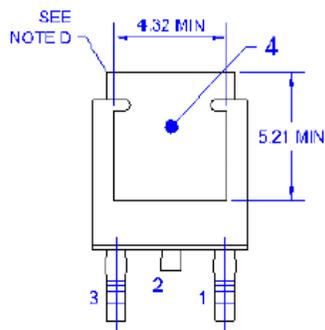
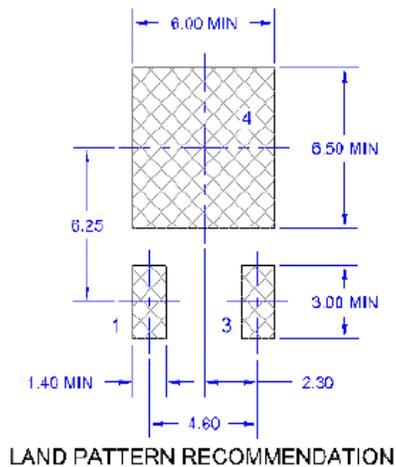
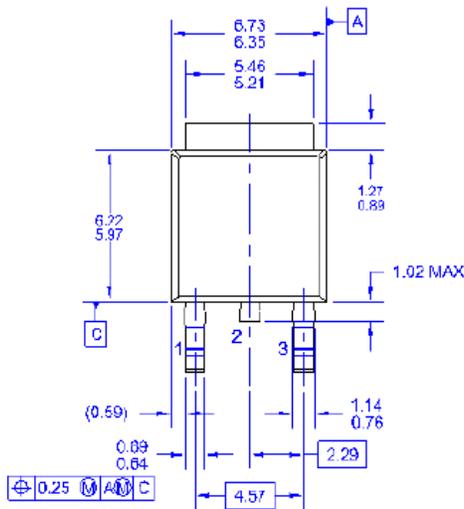


Peak Diode Recovery dv/dt Test Circuit & Waveforms



## Mechanical Dimensions

### D-PAK



- NOTES: UNLESS OTHERWISE SPECIFIED:  
 A) THIS PACKAGE CONFORMS TO JEDEC, TO-262, ISSUE C, VARIATION AA.  
 B) ALL DIMENSIONS ARE IN MILLIMETERS.  
 C) DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.  
 D) HEAT SINK TOP EDGE COULD BE IN CHAMFERED CORNERS OR EDGE PROTRUSION.  
 E) PRESENCE OF TRIMMED CENTER LEAD IS OPTIONAL.  
 F) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS.  
 G) LAND PATTERN RECOMMENDATION IS BASED ON IPC7351A, STD TO220P1003X236-3N.  
 H) DRAWING NUMBER AND REVISION: WKT-T0252A03REV B

Dimensions in Millimeters



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- |                                                                                   |                                                                                   |                                                                                   |                                                                                     |
|-----------------------------------------------------------------------------------|-----------------------------------------------------------------------------------|-----------------------------------------------------------------------------------|-------------------------------------------------------------------------------------|
| 2Cool™                                                                            | F-PFST™                                                                           | PowerTrench®                                                                      | The Power Franchise®                                                                |
| AccuPower™                                                                        | FRFET®                                                                            | PowerXS™                                                                          | the power®                                                                          |
| AX-CAP™*                                                                          | Global Power Resource <sup>SM</sup>                                               | Programmable Active Droop™                                                        | franchise                                                                           |
| BitSiC®                                                                           | Green Bridge™                                                                     | QFET®                                                                             | TinyBoost™                                                                          |
| Build it Now™                                                                     | Green FPS™                                                                        | QS™                                                                               | TinyBuck™                                                                           |
| CorePLUS™                                                                         | Green FPS™ e-Series™                                                              | Quiet Series™                                                                     | TinyCalc™                                                                           |
| CorePOWER™                                                                        | Gmax™                                                                             | RapidConfigure™                                                                   | TinyLogic®                                                                          |
| CROSSVOLT™                                                                        | GTO™                                                                              | ™                                                                                 | TINYOPTO™                                                                           |
| CTL™                                                                              | IntelliMAX™                                                                       |  | TinyPower™                                                                          |
| Current Transfer Logic™                                                           | ISOPLANAR™                                                                        | Saving our world, 1mW/W/kW at a time™                                             | TinyPWM™                                                                            |
| DEUXPEED®                                                                         | Marking Small Speakers Sound Louder and Better™                                   | SignalWise™                                                                       | TinyWire™                                                                           |
| Dual Cool™                                                                        | MegaBuck™                                                                         | SmartMax™                                                                         | TranSiC®                                                                            |
| EcoSPARK®                                                                         | MICROCOUPLER™                                                                     | SMART START™                                                                      | TriFault Detect™                                                                    |
| EfficientMax™                                                                     | MicroFET™                                                                         | Solutions for Your Success™                                                       | TRUECURRENT®*                                                                       |
| ESBC™                                                                             | MicroPak™                                                                         | SPM®                                                                              | µSerDes™                                                                            |
|  | MicroPak2™                                                                        | STEALTH™                                                                          |  |
| Fairchild®                                                                        | MillerDrive™                                                                      | SuperFET®                                                                         | UHC®                                                                                |
| Fairchild Semiconductor®                                                          | MotionMax™                                                                        | SuperSOT™-3                                                                       | Ultra FRFET™                                                                        |
| FACT Quiet Series™                                                                | Motion-SPM™                                                                       | SuperSOT™-6                                                                       | UniFET™                                                                             |
| FACT®                                                                             | mWSaver™                                                                          | SuperSOT™-8                                                                       | VCX™                                                                                |
| FAST®                                                                             | OptoHiT™                                                                          | SupreMOS®                                                                         | VisualMax™                                                                          |
| FastvCore™                                                                        | OPTOLOGIC®                                                                        | SyncFET™                                                                          | VoltagePlus™                                                                        |
| FETBench™                                                                         | OPTOPLANAR®                                                                       | Sync-Lock™                                                                        | XS™                                                                                 |
| FlashWriter®*                                                                     |  |  |                                                                                     |
| FPS™                                                                              |                                                                                   |                                                                                   |                                                                                     |

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**Definition of Terms**

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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